

14701 Firestone Blvd. * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet

Part Number / Ordering Information 1/

SED40HE45LVCT

L Screening^{2/} = None TX = TX Level TXV = TXV Level S = S Level

Lead Orientation

1 = Front Mount

2 = Side Mount

3 = Split Mount

SED40HE45LVCT **Series**

SURFACE MOUNT **40 AMP, 45 VOLTS** LOW VF CENTERTAP SCHOTTKY RECTIFIER

FEATURES:

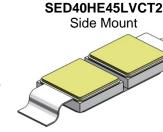
- Low Reverse Leakage
- Low Forward Voltage Drop
- Hermetically Sealed Power Surface Mount Package
- Guard Ring for Overvoltage Protection
- **Eutectic Die Attach**
- 175°C Operating Temperature
- Hot Case Version (Isolated Versions Available Contact Factory)
- Smaller Footprint than TO-25X package
- Weight: 0.65 g typ
- TX, TXV, and Space Level Screening Available^{2/}

MAXIMUM RATINGS (per leg)	Symbol	Value	Units
Peak Repetitive Reverse Voltage and DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A = 100°C)	Io	20	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, 1 pulse, T _A = 25°C)	I _{FSM}	250	Amps
Operating and Storage Temperature	T _{OP} & T _{stg}	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	R _{eJC}	1.25	°C/W

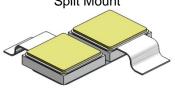
Notes:

1/ For ordering information, price, operating curves, and availability - contact factory. 2/ Screening based on MIL-PRF-19500. Screening flows available on request.





SED40HE45LVCT3 Split Mount





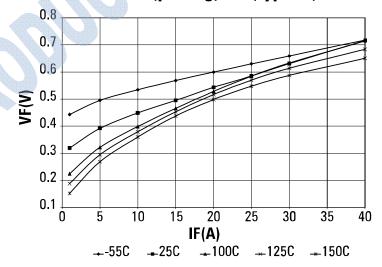
Solid State Devices, Inc.

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SED40HE45LVCT Series

ELECTRICAL CHARACTERISTICS (p	er leg)	Symbol	Typical	Maximum	Unit
Instantaneous Forward Voltage Drop (I _F = 5 A _{DC} , 300 - 500 µsec pulse)	$T_A = -55$ °C $T_A = 25$ °C $T_A = 125$ °C	$egin{array}{c} oldsymbol{V_{F1}} \ oldsymbol{V_{F2}} \ oldsymbol{V_{F3}} \end{array}$	0.45 0.40 0.30	0.425	V _{DC}
Instantaneous Forward Voltage Drop (I _F = 10 A _{DC} , 300 - 500 µsec pulse)	$T_A = -55$ °C $T_A = 25$ °C $T_A = 125$ °C	V _{F4} V _{F5} V _{F6}	0.54 0.45 0.38	0.48 0.43	V _{DC}
Instantaneous Forward Voltage Drop (I _F = 20 A _{DC} , 300 - 500 μsec pulse)	$T_A = -55$ °C $T_A = 25$ °C $T_A = 125$ °C	V _{F7} V _{F8} V _{F9}	0.60 0.55 0.52	- 0.59 -	V _{DC}
Reverse Leakage Current (Rated V _R , 300 µsec pulse minimum)	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$ $T_A = 125^{\circ}C$	I _{R1} I _{R2} I _{R3}	0.125 20 25	1 - 50	mA
Junction Capacitance (T _A = 25°C, f = 1 MHz)	$V_R = 5V$ $V_R = 10V$	C _{J1} C _{J2}	720 540	900	pF

SED40HE45LV (per leg): VF(typical) vs. IF



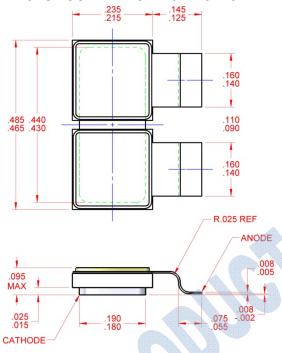


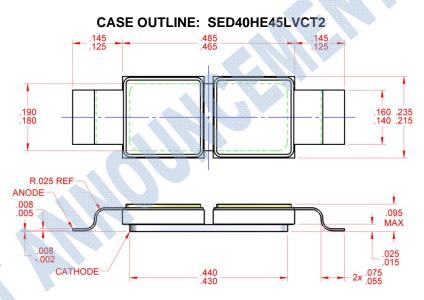
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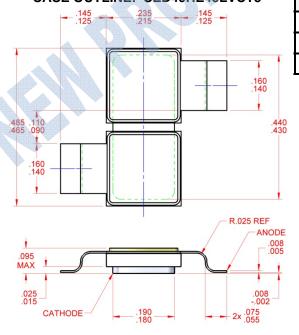
SED40HE45LVCT Series

CASE OUTLINE: SED40HE45LVCT1





CASE OUTLINE: SED40HE45LVCT3



Configuration	Base	Leads
Common Cathode (CT)	Cathode	Anode